Diode Semiconductor Device - Page 1 of 1



Inclos	ure Material:
Metal	
Overa	II Length:
1.253	inches
Mount	ting Facility Quantity:
1	
Joint	Electronic Device Engineering Council/jedec/case Outline Designatior
Do-4	
Mount	ting Method:
Thread	ded stud
Featu	res Provided:
Herme	tically sealed case
Overa	II Width Across Flats:
0.437	inches
Threa	d Size:
0.190	inches
Semic	conductor Material:
Silicon	
Voltag	e Rating In Volts Per Characteristic:
100.0	reverse voltage, peak
Curre	nt Rating Per Characteristic:
20.00	amperes forward current, average
Maxin	num Operating Tempurature Per Measurement Point:
175.0	degrees celsius junction
Threa	d Series Designator:
Unf	
Termi	nal Type And Quantity:
1 tab,	solder lug and 1 threaded stud
Shelf	Life:
N/a	
Unit C	of Measure:
Demil	itarization:
No	
Fiig:	
A110a	0